

TOSHIBA PHOTO DARLINGTON TRANSISTOR SILICON NPN EPITAXIAL PLANAR

TPS605, TPS605 (LB)

HOME ELECTRIC EQUIPMENT SUCH AS AUDIO, VCR, ETC.

OA EQUIPMENT SUCH AS COPYING MACHINE, PRINTER, ETC.

OPTICAL SWITCH

- Micro-package (epoxy resin package)
 - Double end type : TPS605
 - DIP type : TPS605 (LB)
- Mountable at a 2.5mm pitch
- High sensitivity : $I_L = 0.2\text{mA}$ (Min.)
- Half value angle : $\theta_{\frac{1}{2}} = \pm 20^\circ$ (TYP.)
- Maximum distance when used as an optical switch
 - TLN104 at DC drive $\approx 100\text{mm}$ at TPS605 $I_L \approx 500\mu\text{A}$

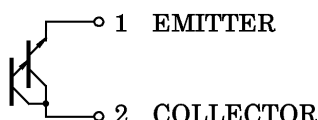
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Collector Voltage	V _{ECO}	5	V
Collector Current	I _C	40	mA
Collector Power Dissipation	P _C	75	mW
Collector Power Dissipation Derating (Ta>25°C)	ΔP _C /°C	−1	mW/°C
Operating Temperature Range	T _{opr}	−25~85	°C
Storage Temperature Range	T _{stg}	−30~100	°C
Soldering Temperature (3s)	T _{sol}	260	°C

RECOMMENDED OPERATING CONDITIONS

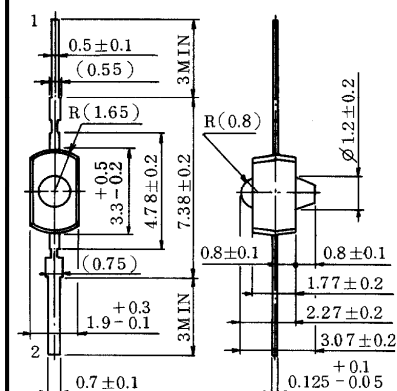
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{CC}	—	5	16	V
Operating Temperature	T _{opr}	0	—	70	°C

PIN CONNECTION



Unit in mm

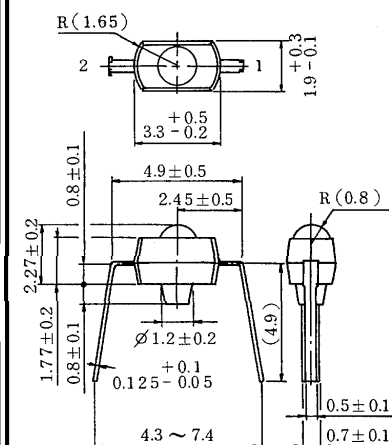
TPS605



() : REFERENCE VALUE

JEDEC	—
EIAJ	—
TOSHIBA	0-2C1

TPS605 (LB)



() : REFERENCE VALUE

JEDEC	—
EIAJ	—
TOSHIBA	0-2C101

Weight : 0.08g (TYP.)

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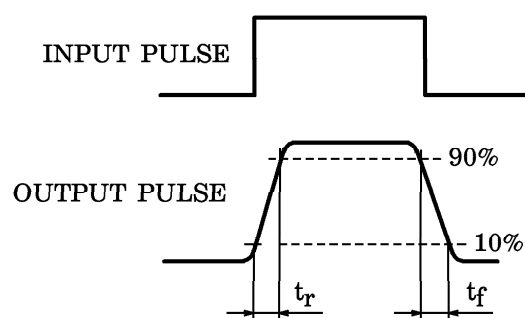
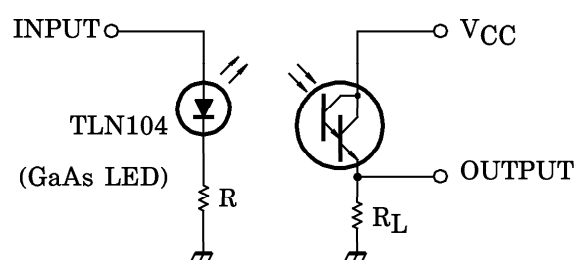
OPTO-ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Dark Current	$I_D (I_{CEO})$	$V_{CE} = 16V, E = 0$	—	0.03	0.25	μA
Light Current (Note 1)	I_L	$V_{CE} = 3V, E = 0.01mW / cm^2$ (Note 2)	0.2	1	—	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 0.08mA, E = 0.01mW / cm^2$	—	0.9	12	V
Peak Sensitivity Wavelength	λ_P	—	—	720	—	nm
Half Vaule Angle	$\theta_{\frac{1}{2}}$	—	—	± 20	—	°
Switching Time	Rise time	$V_{CC} = 5V, I_C = 10mA$ $R_L = 100\Omega$ (Note 3)	—	200	—	μs
	Fall Time		—	150	—	

Note 1. I_L Classification A : 0.2~1.2mA, B : 0.8~4.8mA

2. Color temperature = 2870°K, Standard Tungsten Lamp

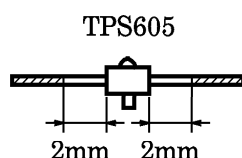
3. Switching time test circuit



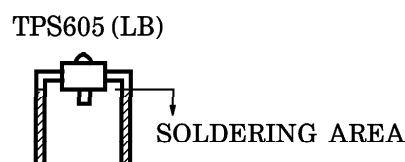
PRECAUTION

Please be careful of the followings.

1. If the lead is formed, the lead should be formed at a distance of 0.8mm from the body of the device. Soldering shall be performed after lead forming. However, in case of TPS605 (LB), no lead forming shall be performed.
2. Soldering shall be performed within the range show below.



AREA 2mm AWAY FROM
THE PACKAGE ENDS



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